

**DB3 Series**

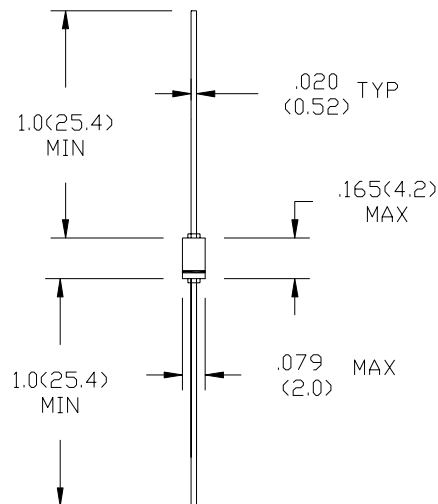
**Applications**

Gate-control circuits and power oscillator designs

**Maximum Ratings and Electrical Characteristics**

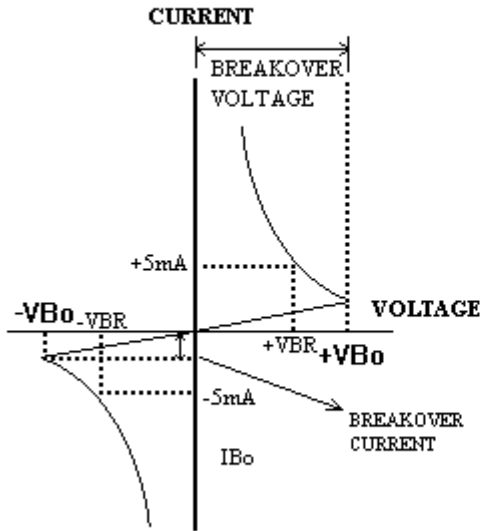
PARAMETERS	SYMBOL	DB3	DB4	UNITS
Breakover Voltage	$+V_{BO}, -V_{BO}$			VOLT
		28	35	Min
		32	40	Typ
		36	45	Max
Breakover Voltage Symmetry	$ (+V_{BO}) - (-V_{BO}) $	3	3	VOLT Max
Dynamic Breakback Voltage	$  V_{BO}  -  V_{BR}  $	5	5	VOLT Min
Breakover Current	$+I_{BR}, -I_{BR}$	100	100	$\mu$ A Max
Peak Pulse Current for 10 $\mu$ S, 120pps, $T_A \leq 40^\circ\text{C}$	$I_P$	2.0	2.0	AMP Max
Cases: DO-35 Molded Glass				

**Mechanical Dimensions: In Inches / mm**

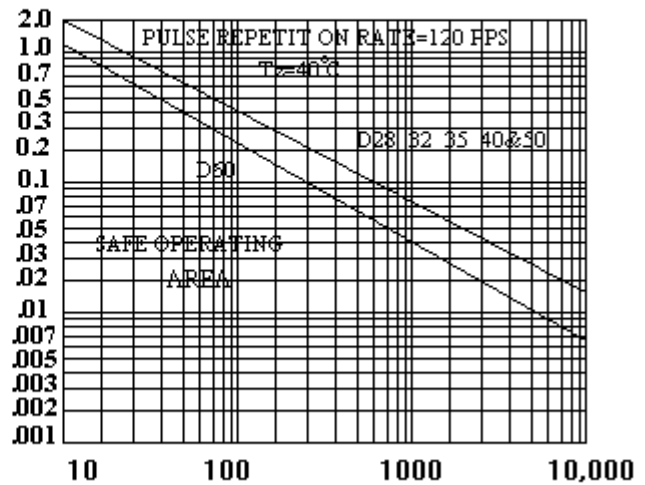


**DO-35**

**FIGURE 1--V-I CHARACTERISTICS**



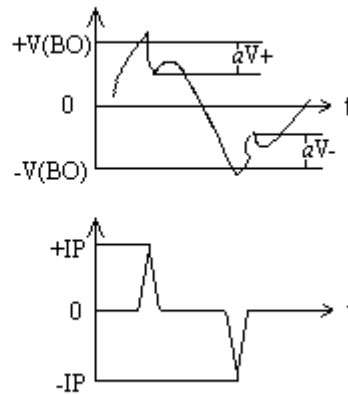
**FIGURE 2-REPETITIVE PEAK ON-STATE CURRENT VS PULSE DURATION**



**FIGURE 3-NORMALIZED VBO CHANGE VS JUNCTION TEMPERATURE**

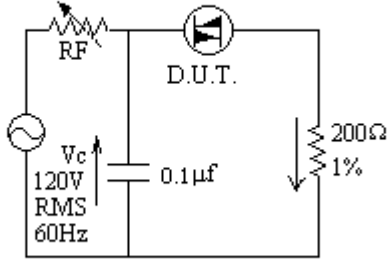


**FIGURE 4-TEST CIRCUIT WAVEFORMS (SEE FIGURE 5)**



Technical Data  
Data Sheet 1280, Rev. A

**FIGURE 5-CIRCUIT USED TO MEASURE  
DIAC CHARACTERISTICS**



**\*ADJUST FOR ONE FIRINGIN HALF CYCLE**

**TECHNICAL DATA**

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